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## WHAT IS CLAIMED IS:

- 1. An electron-emitting device comprising:
- (A) fiber comprising carbon as a main ingredient, and
- (B) a layer made of oxide composed of a material selected from Ti, Zr, Nb, and Al or a layer made of oxide semiconductor composed of a material selected from Ti, Zr, and Nb,

wherein the fiber comprising carbon as a main ingredient is disposed on the layer and the fiber comprising carbon as a main ingredient partially contains Pd.

- 2. The electron-emitting device according to claim 1, wherein the Pd is disposed at a position where the fiber comprising carbon as a main ingredient is in contact with the layer.
- 3. The electron-emitting device according to 20 claim 1, wherein the Pd is disposed on an end of the fiber comprising carbon as a main ingredient or on an intermediate point of the fiber comprising carbon as a main ingredient.
- 25 4. The electron-emitting device according to claim 1, wherein the fiber comprising carbon as a main ingredient is grown via Pd particles disposed on the

layer.

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- The electron-emitting device according to claim 1, wherein the fiber comprising carbon as a main ingredient includes a graphen.
  - 6. The electron-emitting device according to claim 1, wherein the fiber comprising carbon as a main ingredient includes a plurality of layered graphens.
  - 7. The electron-emitting device according to claim 6, wherein the plurality of graphens is layered in an axial direction of the fiber comprising carbon as a main ingredient.
  - 8. The electron-emitting device according to claim 1, wherein the fiber comprising carbon as a main ingredient is made of graphite nanofiber, carbon nanotube, amorphous carbon, or a mixture containing more than one of these.
  - 9. The electron-emitting device according to claim 1, further comprising:
- a first electrode on a surface of a substrate, and
  a second electrode disposed on the surface of the
  substrate and spaced apart from the first electrode,
  means for applying a potential higher than the

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first electrode to the second electrode,

wherein at least a part of the layer is disposed on the first electrode.

- 5 10. The electron-emitting device according to claim 9, wherein the first electrode is larger in thickness than the second electrode.
  - 11. The electron-emitting device according to claim 9, wherein the fiber comprising carbon as a main ingredient is disposed farther than the second electrode from the surface of the substrate.
  - 12. The electron-emitting device according to claim 9, wherein the surface of the substrate has a step height such that the first electrode is higher than the second electrode.
- An electron source comprising a plurality of
   electron-emitting devices,

wherein the electron-emitting device is an electron-emitting device according to any one of claims 1 to 12,

25 14. An image-forming apparatus comprising: an electron source according to claim 13, and an anode where an electron emitted from the

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electron source comes into collision.

- 15. The image-forming apparatus according to claim 14, wherein the anode has a phosphor.
  - 16. An electron-emitting device comprising:
- (A) first and second electrodes disposed with a gap on a surface of a substrate,
- (B) a plurality of fibers each comprising carbon as a main ingredient electrically connected with the first electrode, and
- (C) means for applying a voltage higher than the first electrode to the second electrode,

wherein ends of the plurality of fibers each comprising carbon as a main ingredient are higher than a surface of the second electrode from the surface of the substrate, and

a layer made of oxide composed of a material selected from Ti, Zr, Nb, and Al or a layer made of oxide semiconductor composed of a material selected from Ti, Zr, and Nb is disposed between the first electrode and the plurality of fibers each comprising carbon as a main ingredient.

17. The electron-emitting device according to claim 16, wherein the layer and the plurality of fibers each comprising carbon as a main ingredient are

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connected to each other via a catalyst material.

- 18. The electron-emitting device according to claim 17, wherein the catalyst material is a material selected from Pd. Ni. Fe. Co. and an allow of these.
- 19. The electron-emitting device according to claim 16, wherein the first electrode is larger in thickness than the second electrode.
- An electron source comprising a plurality of arranged electron-emitting devices,

wherein the electron-emitting device is an electron-emitting device according to any one of claims 16 to 19.

- 21. An image-forming apparatus comprising: an electron source and an image-forming member
- 20 wherein the electron source is an electron source according to claim 20.
  - 22. An electron-emitting device comprising:
  - (A) fiber comprising carbon as a main ingredient,
  - (B) a layer made of oxide composed of a material selected from Ti, Zr, Nb, and Al or a layer made of oxide semiconductor composed of a material selected

from Ti, Zr, and Nb,

wherein the fiber comprising carbon as a main ingredient is disposed on the layer, and

the fiber comprising carbon as a main ingredient includes a plurality of layered graphens.

- 23. The electron-emitting device according to claim 22, wherein the plurality of graphens are layered in an axial direction of the fiber comprising carbon as a main ingredient.
- 24. The electron-emitting device according to claim 22, wherein the fiber comprising carbon as a main ingredient is grown via Pd particles disposed on the layer.
- 25. The electron-emitting device according to claim 22, wherein the fiber comprising carbon as a main ingredient contains Pd.

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26. An electron source comprising a plurality of electron-emitting devices,

wherein the electron-emitting device is an electron-emitting device according to any one of claims 25 22 to 25.

27. A method for manufacturing an image-forming

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apparatus,

the apparatus comprising an electron source and an image-forming member,

wherein the electron source is an electron source according to claim 26.

- 28. A method for manufacturing an electronemitting device, which includes fiber comprising carbon as a main ingredient, comprising the steps of:
- (A) providing a layer made of oxide composed of a material selected from Ti, Zr, Nb, and Al or a layer made of oxide semiconductor composed of a material selected from Ti, Zr, and Nb,
  - (B) disposing catalyst particles on the layer, and
- (C) heating the substrate on which the catalyst particles are disposed in an atmosphere containing carbon compound.
- 29. The method for manufacturing the electronemitting device according to claim 28, wherein the carbon compound is hydrocarbon gas.
- 30. The method for manufacturing the electronemitting device according to claim 28, wherein the 25 layer is formed on the electrode disposed on the substrate.

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- 31. The method for manufacturing the electronemitting device according to claim 28, wherein the
  layer is formed by the step of forming a conductive
  layer made of a material selected from Ti, Zr, Nb, and
  Al on the substrate and oxidizing a surface of the
  conductive layer.
- 32. The method for manufacturing the electronemitting device according to claim 31, wherein the step of oxidizing the surface of the conductive layer is carried out by the step of forming a material of the catalyst particles on the surface of the conductive layer and oxidizing the material.
- 33. The method for manufacturing the electronemitting device according to claim 28, wherein the catalyst particles are made of a material selected from Pd, Ni, Fe, Co, and an alloy of these.
- 34. A method for manufacturing an electronemitting device, which includes a plurality of electron-emitting devices,

wherein the electron-emitting device is manufactured by the manufacturing method according to any one of claims 28 to 33.

35. A method for manufacturing an image-forming

apparatus, which includes an electron source and an image-forming member,

wherein the electron source is manufactured by the manufacturing method according to claim 34.